Abstract

It has been long known that numerous halide and oxide perovskites can have non-ideal octahedra, showing tilting, rotation, and metal atom displacements. It has also been known that compounds that have at low temperatures a single structural motif ("monomorphous structures") could become disordered at higher temperatures, resulting in non-ideal octahedra as an entropy effect. What is shown here is that in many cubic halide perovskites and some oxides compounds a distribution of different low-symmetry octahedra ("polymorphous networks") emerge already from the minimization of the systems internal energy, i.e., they represent the intrinsic, preferred low temperature pattern of chemical bonding. Thermal disorder effects build up at elevated temperatures on top of such low temperature polymorphous networks. Compared with the monomorphous counterparts, the polymorphous networks have lower predicted total energies (enhanced stability), larger band gaps and dielectric constants now dominated by the ionic part, and agrees much more closely with the observed pair distribution functions. The nominal cubic perovskites (Pm-3m) structure deduced from X-Ray diffraction is actually a macroscopically averaged, high symmetry configuration, which should not be used to model electronic properties, given that the latter reflect a low symmetry local configuration.
I. Introduction

ABX₃ compounds often appear (when X= Oxygen) as ferroelectrics, Mott insulators and transparent conductors, and (when X= halogen) as solar photovoltaic absorbers. They show at low temperatures the low-symmetry monoclinic, orthorhombic or tetragonal ground state structures, and, at higher temperatures the high-symmetry cubic structure. The latter is of great interest in numerous applications. For example, the cubic phases of halide perovskites feature prominently in photovoltaic solar cell applications because of their appropriate solar band gap values, compared to the generally too high gaps of the low symmetry structures. In oxide perovskites such as SrTiO₃, SrVO₃ or BaZrO₃, this cubic phase shows up as an intrinsically monomorphous structure, i.e., having a single structural motif represented crystallographically by a small, repeated unit cell, as illustrated in Fig. 1a.

While octahedral tilting or B atom displacements as a single repeated structural motif are well known in perovskites, we find that removing the standard restriction to such a minimal unit cell size in total energy structural optimization, leads in some perovskites to the formation of a ‘polymorphous network’, manifesting a distribution of different tilt angles and different B-atom displacement in different octahedra, illustrated in Fig. 1(b, c). Such systems cannot be described crystallographically by a small, repeated unit cell, and were generally described as thermally disordered compounds, modelled by high temperature molecular dynamics via time-dependent dynamic motions with entropy-driven disorder. What is different about the polymorphous network illustrated in Fig. 1(b, c) for the cubic halide perovskite FASnI₃ (where FA=CH(NH₃)₂) is that the distribution of local motifs emerges already from the (density functional) minimization of the static, T=0 internal energy of a large supercell, constrained to have the global cubic lattice vectors. This a-thermal distribution represents a correlated set of displacements and is very different from the time-dependent uncorrelated entropic thermal disorder calculated by MD, or from the single sharp monomorphous values of these deformation parameters (shown as vertical blue lines in Fig. 1c). This a-thermal distribution is a statement of the preference of the low temperature chemical bonding (such as s-p hybridized lone pair orbitals of Sn²⁺ and Pb²⁺ encouraging stereochemically off center motions), before thermal agitation sets in. This distribution of local motifs is also different from the periodically repeated ordered double-potential well models that address anharmonic polar fluctuations. The existence of such a polymorphous distribution is easy to miss using standard energy minimization protocols (such as those based on following gradients to the nearest local minimum) but is revealed once one initially applies a random atomic displacement ("nudge") off the cubic sites and explores lower symmetries in the minimization process.

These polymorphous networks represent a different paradigm in understanding cubic halide and oxide perovskites (we use the term polymorphous network, as distinct from structural polymorphs. The former is the case when a single structure exhibits many local motifs, whereas the latter case—not discussed here—pertains to individual phases, each having their own structural motif. Also, our big supercell cannot be called monomorphous: the latter is a single motif, not a single unit cell).

Our finding suggests that the widely discussed single formula unit cubic Pm-3m structure of halide perovskites does not really exist, except as a macroscopically averaged fictitious structural model. Because X-ray diffraction has a rather long coherence length, such
polymorphous systems were often fit in structure refinement models\textsuperscript{11,25} by a macroscopically averaged (“\textit{fictitious monomorphous}”) cubic Pm-3m unit cells. Standard electronic structure calculations\textsuperscript{4,10,13–24} that use input structures directly from crystal databases often modeled the properties of the system (band gaps, absorption spectra, thermodynamic stability, alloy mixing enthalpies) as the property \(<P> = P(S_0)\) of the reported macroscopically averaged monomorphous structure\textsuperscript{26,27} \(S_0\) rather than the average \(P_{\text{obs}} = \Sigma P(S_i)\) of the properties \(\{P(S_i)\}\) of the individual, low symmetry microscopic configurations \(\{S_i; i=1, N\}\).

One expects, as illustrated in this paper for a range of properties, that the properties \(P(S_0)\) of high symmetry cubic structures would differ significantly from the properties \(P(S_i)\) of broken symmetry cubic structures or their average. Significantly, compared to the monomorphous assumption, we show here that the cubic polymorphous network (i) fits much better the observed Pair Distribution Function (PDF), which probes the local environment. The improved depiction of the local structure leads in polymorphous networks to (ii) a significantly lowering of calculated total energies, by \(\sim 70\text{-}150\text{ meV/f.u.}\), and (iii) up to 300\% larger band gaps, on account of the reduced level repulsion afforded by larger octahedral tilting and rotations. The literature calculated MD contribution to increased band gaps is rather small relative to the increase already provided by the polymorphous network which constitutes the kernel structure from which thermal disorder emerges at elevated temperatures. Thus, (iv) the band gap renormalization energy (\(\sim 200\text{ meV}\)) is now closer to experiment relative to the values computed with respect to the band gap of the monomorphous model (390-640 meV). (v) Use of the polymorphous structure leads to the reversal of the predicted sign of the mixing enthalpies of the solid solutions from negative (ordering-like; not seen experimentally) to positive (experimentally observed phase-separating), in better agreement with observations. (vi) Remarkably, despite the existence of a distribution of motifs, the calculated band structure (unfolded to the primitive Brillion zone from the supercell) shows sharp band edge states and a correspondingly fast rise of the absorption spectrum, rather than the expectation based on ordinary disorder models where disorder fills—in the band gap region by localized states, and leads to a broad and slow rising absorption tail. Finally, relative to the monomorphous case, (vii) polymorphous networks have a much larger (by \(\sim 51\%\)) calculated dielectric constant, where the ionic contribution now dominates the electronic contribution as expected from near ferroelectrics. The polymorphous approximant could thus serve as a very useful practical structure to use with standard band structure approaches to predict properties, replacing the fictitious monomorphous structures used now.

The establishment of the polymorphous nature of such cubic perovskites—both halides and oxides—defines a broader principle of broken-symmetry systems manifesting a range of microscopic configurations whose physical properties can be very different than the often-assumed macroscopic average.
Figure 1: Structures of monomorphous (a) and polymorphous (b) halide perovskite FASnI₃, and the distribution functions (c) of various octahedral deformations obtained by minimization of the internal energy in Density Functional supercell calculations. The panels in (c) show the distribution functions of octahedral tilting along x/y/z (top panel), B site off-center displacement (middle panel), and the volumes of individual octahedra (bottom panel). Red and blue solid lines refer to Polymorphous and monomorphous networks, respectively. The supercell structures were optimized by keeping fixed the cubic cell shape. The B-site off-center motions are found to include primarily motion toward the edge of octahedra, and toward the face of octahedra. Computational methods and results for other halide perovskites are shown in Supplementary S1 and S2, respectively.

II. Ambiguities and contradictions regarding the assumed monomorphous cubic structure

The nominally cubic phase of halide perovskites is the leading candidate for high efficiency solar cells, (reaching 24% as tandem²⁸), enabled by band gaps in the solar range of 1-2 eV, sharp absorption edges, and long carrier lifetime. The question addressed here is what is the actual atomic arrangement of this all-important cubic phase⁷,¹²,²⁹,³⁰. A number of observations cast doubt on its traditional description as a monomorphous cubic perovskite:

Structure refinement based on periodic monomorphous cells does not lead to a satisfactory fit to the data: X-ray structural studies²⁹ have labeled it as a Pm-3m cubic structure. However, structural refinement within a monomorphous, single formula unit structure could reach a good refinement only by assuming model parameters (such as anisotropic, non-spherical atoms and displaced X sites⁷,¹⁰,²⁹) that in the single formula unit model cannot possibly describe a periodic crystalline network, (and thus, cannot be used in a Schrödinger equation to predict electronic structure and optical properties). Similarly, comparing the measured Pair Distribution Function (PDF) of MAPbI₃ (Fig. 2a) with the DFT-calculatio
(method details are described in Supplementary S-1) for the monomorphous cubic structure (Fig. 2b) shows qualitative disagreements, especially for the peaks P3a (describing Pb-Pb and Pb-I distances) and P3b (describing Pb-I). Again, a good fit to experiment within a monomorphous ansatz was possible only when non-periodic model with effective parameters was fitted. Supplementary S-3 compares the PDF of double well model (without fitting parameters, unlike Ref 30) with the present results.

Table I: Experimental band gaps ($E_g^{exp}$), and calculated band gaps by using PBE functional for different structures of CsPbI$_3$, CsSnI$_3$, MAPbI$_3$, FAPbI$_3$ and FASnI$_3$.

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<tr>
<th></th>
<th>$E_g^{exp}$ (eV)</th>
<th>Monomorphous cubic $E_g$ (eV)</th>
<th>Polymorphous cubic $E_g$ (eV)</th>
<th>Tetragonal $E_g$ (eV)</th>
<th>Orthorhombic $E_g$ (eV)</th>
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<tr>
<td>CsPbI$_3$</td>
<td>1.73$^a$</td>
<td>1.32</td>
<td>1.86</td>
<td>1.43</td>
<td>1.81</td>
</tr>
<tr>
<td>CsSnI$_3$</td>
<td><strong>1.30$^b$</strong></td>
<td>0.27</td>
<td>0.92</td>
<td>0.43</td>
<td><strong>0.82</strong></td>
</tr>
<tr>
<td>MAPbI$_3$</td>
<td>1.57$^a$</td>
<td>1.37</td>
<td>1.83</td>
<td>1.47</td>
<td>1.67</td>
</tr>
<tr>
<td>FAPbI$_3$</td>
<td>1.48$^a$</td>
<td>1.41</td>
<td>1.70</td>
<td>1.38</td>
<td>--</td>
</tr>
<tr>
<td>FASnI$_3$</td>
<td><strong>1.41$^b$</strong></td>
<td><strong>0.43</strong></td>
<td>1.06</td>
<td>0.49</td>
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**Gap anomaly**: Whereas the measured gaps of cubic FASnI$_3$ is ~100 meV larger than that of orthorhombic CsSnI$_3$, calculations using the monomorphous cubic (M-cubic) structure (Table I and Fig. S-4 in supplementary) got persistently the reverse order of magnitude of gaps, confusing the selection of materials with target band gaps for tandem solar cells. Likewise, for MAPbI$_3$, calculations of M-cubic structures (using high-precise GW functional with spin-orbit coupling) gives a 530 meV lower gap than the calculated gap of orthorhombic structure. Experimentally it is 40 meV larger$^5$. Table S-4 shows that this inconsistency persists when advanced exchange and correlation functionals are used.

**Greatly overestimated temperature band gap renormalization energy**: When the M-Cubic phase was used to approximate the low temperature phase, the calculated band gap renormalization energy (difference in band gaps at high vs low temperature) turned out to be 390-640 meV$^8$, far larger than the measured values$^5$, typically ~50 meV.

**Reverse sign of mixing enthalpy**: The alloy mixing enthalpy $\Delta H(A_x B_{1-x})$ measures the enthalpy $H(A_x B_{1-x})$ of an A$_x$B$_{1-x}$ alloy taken with respect to equivalent amounts of the energies of the constituents $xH(A)+(1-x)H(B)$. When $H(A)$ and $H(B)$ were calculated from the macroscopically averaged M-cubic structure$^{27}$, the resulting $\Delta H(A_x B_{1-x})$ is often negative, implying long range ordering at low temperature, which was never observed.

**The macroscopically averaged configuration is phonon unstable**: Some cubic perovskite phases can be stable as an intrinsically monomorphous phases, e.g., SrTiO$_3$ or BaZrO$_3$. That the M-Cubic structure cannot be physically realized in some other perovskites is obvious from the appearance of numerous dynamically unstable phonon branches in a broad range of wavevectors in the DFT calculated harmonic phonon dispersion curves$^{33}$ shown in Fig. S-1 in
Supplementary S-1b (similarly unstable phonons were reported by refs\textsuperscript{34–37}). Such dynamic instabilities imply that the cubic Pm-3m monomorphous structure must be replaced by a stable structure, as discussed for semiconductors in Ref\textsuperscript{38}. At low temperature, the replacing structures are the orthorhombic or trigonal ground state phases, whereas at high temperature, anharmonic phonon-phonon interactions can stabilize the cubic CsSnI\textsubscript{3}\textsuperscript{9}.

Despite the inconsistencies surrounding the use of monomorphous structures described above, such structures continue to be used as input to band structure calculations or to X-ray refinement, perhaps because one cannot use the structure deduced from PDF fits because these structures are non-periodic, and using snap shots from molecular dynamics is not a popular solution either because MD is a specialized technique, that does not easily lends itself to electronic structure theory. Consequently, the monomorphous representation of single unit cell is very popular for both X-ray and neutron diffraction refinement\textsuperscript{14}, calculation of band structures\textsuperscript{16,17,39} and band offsets\textsuperscript{20,21}, phonons\textsuperscript{34–37}, qualitative description of trends based on crystal symmetry\textsuperscript{20}, including also topological properties\textsuperscript{40}, and high throughput calculations and machine learning for discovery and design\textsuperscript{19} of new halide perovskites.

We next show how the replacement of the monomorphous ansatz by the lower energy polymorphous network removes these, and other inconsistencies.

Table II: The differences $\Delta E_{\text{tot}}$ in total energy of large supercells with free relaxation (polymorphous network) and the corresponding minimal cell structure (monomorphous approximation) by using PBE functional. $\Delta E_{\text{g}}$ (meV) gives the corresponding change in band gaps between large relaxed vs minimal unit cells. Absolute values of gaps are given in Table I. This table illustrates that the cubic phase is naturally polymorphous (total energy is stabilized by allowing different local environments), whereas the orthorhombic phase is intrinsically monomorphous i.e., has essentially the same description in a monomorphous and polymorphous representation. The small positive values of $\Delta E_{\text{tot}}$ in the third and fourth columns are due to the numerical uncertainties (e.g., k-mesh of different lattice types). The estimated uncertainty is 20-30 meV/f.u. for total energies and ~0.15 eV for band gaps.

<table>
<thead>
<tr>
<th></th>
<th>$\Delta E_{\text{tot}}$ (meV/f.u.)</th>
<th>$\Delta E_{\text{g}}$ (meV)</th>
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<tbody>
<tr>
<td></td>
<td>Cubic</td>
<td>Tetragonal</td>
</tr>
<tr>
<td>MAPbI\textsubscript{3}</td>
<td>-72</td>
<td>2</td>
</tr>
<tr>
<td>CsPbI\textsubscript{3}</td>
<td>-123</td>
<td>9</td>
</tr>
<tr>
<td>CsSnI\textsubscript{3}</td>
<td>-55</td>
<td>0</td>
</tr>
<tr>
<td>FAPbI\textsubscript{3}</td>
<td>-149</td>
<td>-1</td>
</tr>
<tr>
<td>FASnI\textsubscript{3}</td>
<td>-144</td>
<td>-10</td>
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III. The energy stabilization of the polymorphous structure

Since the high temperature thermally disordered cubic phase (described, e.g., via molecular dynamics) cannot be properly thought of as developing from the monomorphous, 1 f.u./cell structure that is fictive, we seek to identify the kernel structure from which the high T behavior ...
emanates. To do so we search for the structure that minimizes the \( T = 0 \) internal energy of the cubic lattice, however, without restricting the cell to a single formula unit, a restriction that does not allow general octahedral deformations without violating periodicity. We thus increase the cell size from 1 f.u. (5 atoms) to 32 f.u. (160 atoms when the cation \( A = \) inorganic ions), while retaining the cubic lattice vectors. To avoid locking into a local minimum, we apply random atomic displacements (up to 0.25 Å) before total energy/force minimization is applied. Note that the explored DFT Born-Oppenheimer surface includes, in principle, full anharmonicities. As in any calculation of a supercell with positionally relaxed atoms, here too there are standard convergence tests as a function of supercell size and the largest magnitude of force \( F \) allowed on atoms that is used as criterion for declaring the calculation converged. For the latter we use \( F_{\text{max}} < 0.01 \text{ eV/Å} \). When this is changed to \( F_{\text{max}} < 0.05 \text{ eV/Å} \) the changes in the distribution function of Fig. 1 are less than 0.25%.

In conventional, intrinsically monomorphous compounds such as diamondlike Si, III-V compounds such as GaAs, or II-VI compounds such as rock-salt MgO or zincblende ZnS, the total energies per formula unit of a large supercell and small supercell are the same, within computational precision. We see from Table II that for halide perovskites, some structures are intrinsically monomorphous, e.g., the tetragonal structure. The total energy per formula unit of these phases does not change within computational uncertainty if calculated in small or large supercells. On the other hand, the cubic phases are not stable in a monomorphous structure. The total energy of the respective cubic phases is stabilized by polymorphism by up to \( \Delta E_{\text{tot}} \sim 150 \text{ meV/f.u.} \). Thus, the polymorphous state is not an excited state but an alternative to the fictitious cubic monomorphous model. Thus, the \( T=0 \) distortions in the tetragonal cell are not polymorphous as are the distortions in the cubic cell shown in Fig. 1. Table II further shows that the cubic phase has a significantly larger band gap in the polymorphous structure, whereas the real monomorphous ground state phases have but a negligible shift in band gap when large supercells are explored.

**IV. The PDF of the energy-minimizing polymorphous network**

To examine if the energy minimizing geometry is realistic, we compare in Fig. 2 the ab-initio calculated pair distribution function (PDF) with the experimental result\(^{30}\) (shown by black line Fig. 2a), both for short and intermediate interatomic separations (left side panels) and long range separations (right side panels). Previous PDF measurements and simulations\(^{41}\) often fit the data in a small unit cell by introducing parameters\(^{30}\) such as atoms having non spherical shapes, even changing the values of the observed lattice parameters, and altering Wyckoff positions with respect to XRD measurement in search for an effective model that fits the PDF. The ensuing structural models are generally non-periodic, and the description of atoms as finite, shaped objects is incompatible with the way crystal structures are used as input in periodic band structure calculations. Thus, no bridge connects such PDF to other predicted properties. PDF. We recall that sometimes the procedure of generating a crystal structure from PDF measurements used large cells as well\(^{29}\) but this was a fit to experiment, not a prediction. Such fitting procedures with large cells face the problem of over fitting because of insufficient data.
with respect to the number of fitting degrees of freedom. This problem does not exist in variational total energy minimization.

The present method of calculation of the PDF is different. It uses large supercell with hundreds of atoms, offering the opportunity to stick to the conventional description of atoms as shapeless points in a periodic array; the ensuing structure is obtained by first principles, not fitting and then directly usable in electronic structure calculation using any standard band structure method. This is consequential as it provides a direct bridge between PDF and electronic properties. The reason that our present approach is feasible while conventional PDF fitting often resorts to small unit cells is the use in the current work fully constrained energy minimizing approach with respect to all 3N-6 degrees of freedom for N atoms without introducing any fitting parameter. To minimize finite size effects, we use a padding of the relaxation-active central supercell by additional bulk-like halide perovskite material all around the central cell. This reduces periodicity errors.

**Figure 2:** Measured\(^{20}\) (black line in a), and DFT-calculated (a and b) PDF for MAPbI\(_3\) shown at low interatomic distances (left panels) and longer interatomic distances (right panels) with uniform U\(_{ii}\) = 0.01 Å\(^2\) for all the atoms. The red line in (a) refers to the DFT predicted PDF of the 32 f.u./cell polymorphous network; as described in supplementary material S-1a, 32 additional f.u.(“padding”) were added non-self consistently to the central cell to reduce periodicity errors. The vertical arrows in (a) indicate bond lengths in the ABX\(_3\) structure. (b) is calculated within the monomorphous 1 f.u. cubic cell and deviates significantly from experiment, especially in the 6-8 Å region of the P3a (i.e., Pb-Pb and Pb-I) and P3b (i.e., Pb-I) peaks. All calculations were done by using DFT-calculated periodic structures without fitted model parameters. The difference between experiment and calculated PDF are depicted using green lines.

We see from Fig. 2b, that the monomorphous structure (with a uniform ADPs U\(_{ii}\) = 0.01 Å\(^2\) for each Pb and I atom to roughly include the finite temperature effect) gives rather poor agreement with experiment (see, in particular the split three peaks at 6-8 Å). The red line in
Fig. 2a shows the PDF calculated from the polymorphous network with the same ADPs. Given that our large supercell calculation is generated from total energy minimization, we consider the agreement in Fig. 2a between theory and experiment as good.

The detailed discussion of comparison is illustrated in Supplementary S-1a. We show in Supplementary Fig. S-0 the PDF profiles with different ADPs, illustrating that in using the polymorphous network one does not require such large ADP values as needed to fit the data using the monomorphous structure. Fig. S-0 shows that the polymorphous network gives better PDF than the monomorphous structure or the double well model.

The crystallographic structure file that produces this good agreement with the observed PDF has been used for all calculations of the electronic structure in this paper.

V. Consequences of cubic polymorphous networks on electronic properties

Because the polymorphous networks manifest lower local symmetries than the global averaged symmetry sensed by X-Ray diffraction (embodied by the fictitious monomorphous structure), polymorphous electronic structure calculations that ‘see’ local symmetries produce new, previously unappreciated features:

Correcting the band gap anomaly: Polymorphism increases significantly the band gap relative to the monomorphous ansatz (Fig. 3). There are a number of attempts in the literature to explain the effect of octahedral modes on the band gap of orthorhombic perovskites, such as level repulsion between B-p and X-p orbitals or dimensionality. To isolate the various effects, we create a monomorphous cell replicated periodically a few times and imposed (a) B atom displacement at constant volume, then at relaxed volume, and (b) Octahedral tilting in fixed volume then in relaxed volume. Fig. S-7 shows the results, revealing that (a) B atom displacements at constant volume increase the gap. Such displacements increase the volume; relaxing to the new volume then gives additional band gap increases. (b) Octahedral tilting at fixed volume has a small effect on the gap. But tilting increases the volume; relaxing to the new volume increases the gap. B atom displacement has the larger effect.

In general, the magnitude of calculated band gaps depends on (i) the structural input (here, monomorphous vs polymorphous) as well as on (ii) the functional used to describe interelectronic interactions in DFT. As to (ii), it is well known that currently used DFT functionals (LDA, GGA, etc.) systematically underestimate the magnitude of the band gap even when the structure is known precisely (e.g., Si or GaAs). The standard cure for this underestimation is also known—using GW, SOC etc. If the structural input (i) is known (as in ground state orthorhombic perovskites which is intrinsically monomorphous) such methods (ii) (see refs) can actually predict the band gap correctly. We find (Fig. 3) that on the other hand when the compound is intrinsically polymorphous (as in the cubic phase of the perovskites), using the incorrect monomorphous structurer as input, one can underestimated the gap by up to 300%. Here we do not focus on getting the exact absolute magnitudes of the band gaps but wish instead to understand the importance of the structural representation on the trends in the gaps in a series of compounds (as shown in Table I and Fig. S-4). Future
calculations using better functionals will likely bring the absolute gap value for intrinsically polymorphous cases closer to experiment.

To qualitatively assess which compounds have the largest increase in band gap in polymorphous relative to monomorphous, supplementary S-5 depicts the respective band gap shifts $E_g$(Poly) - $E_g$(Mono) as well as $E_g$(MD) - $E_g$(mono) vs the tolerance factor. This shows that compounds that have tolerance factor significantly lower than 1 (i.e., likely unstable in the monomorphous structure) have the largest polymorphic effects, consistent with the view that polymorphism is associated with cubically unstable structures.

Figure 3: Band gap values of the DFT monomorphous cubic (M-cubic, blue), the polymorphous cubic (P-Cubic, green), and literature Molecular Dynamics (MD, red). The MD values in (a) come from Mladenović et al. who used the LDA functional; and in (b) from Wiktor et al. who used the rVV10 functional. NH$_4^+$ is included as an example of a molecule with small effective radius even though it does not have the perovskite structure. All values for M-cubic and P-cubic were calculated with the functionals as in the respective MD results. The insert in (a) shows the reason for the increase of band gap due to octahedral deformation: the valence band maximum is formed due to level repulsion between the s orbital of the B atom and the p orbitals of the halogen X. Octahedral deformations decrease the relevant repulsion matrix element, thus increasing the band gap.

Reducing significantly the band gap renormalization error: The shifts of band gaps due to temperature are generally calculated as the shift between finite temperature gap $E_{MD}(T)$ from molecular dynamics, and a low temperature reference band gap $E_{LT}$. Fig. 3 also shows the comparison of the band gaps obtained from the polymorphous network (T=0, minimization of the internal energy alone), with the band gaps obtained in the literature using finite temperature Molecular Dynamics. We used precisely the same exchange correlation functionals and lattice constants as in the respective MD calculations to assure consistency of the results. We see that the MD gaps are slightly higher but very similar to the P-Cubic gaps, consistent with the view that the polymorphous structure derived from minimizing the internal energy captures the leading spectrum of distortions that control the band gaps at higher temperatures. Additional disorder effects introduced specifically by entropy lead to additional small increase
in the band gap as temperature rises. In contrast to what Mladenović et al.\textsuperscript{6} and Wiktor\textsuperscript{8} et al. did (use a monomorphous structure at T=0 as reference to calculate the renormalization energy with respect to the MD gap at high T), we define the renormalization energy as the difference of MD gap with respect to the polymorphous network. The latter approach we use gives ~200 meV renormalization, very close to experiment, while the approach of Wiktor et al.\textsuperscript{8} gives a 390-640 meV renormalization.

**Restoring the correct trend among the band gaps of FASnI\textsubscript{3} vs CsSnI\textsubscript{3}:** The anomalous orders of band gaps of cubic FASnI\textsubscript{3} vs orthorhombic CsSnI\textsubscript{3}, and that of cubic MAPbI\textsubscript{3} vs orthorhombic MAPbI\textsubscript{3} result from modeling the cubic phase in a monomorphous fashion. This is fixed by using the correct P-cubic gaps (Fig. S-4 in supplementary and Table I) showing that, in agreement with experiment\textsuperscript{5,42}, the band gap of CsSnI\textsubscript{3} is smaller than that of FASnI\textsubscript{3}, whereas the band gap of CsPbI\textsubscript{3} is larger than that of FAPbI\textsubscript{3}. These opposing trends can be understood by noting that octahedral distortions raise the band gap, and by analyzing the relative distortions for each of these compounds, shown in Fig. 1 for FASnI\textsubscript{3} and for other halide perovskites in Supplementary Fig. S-2. The distortions calculated for FASnI\textsubscript{3} are much larger than those of CsSnI\textsubscript{3} (mainly off-center), leading to a larger band gap in the former. On the other hand, the trend is the opposite for the Pb compounds, having larger tilting angles in CsPbI\textsubscript{3} compound relative to FAPbI\textsubscript{3} and consequently the former presenting larger gaps.

![Figure 4](image-url)

**Figure 4:** (a) The ‘Spaghetti-like’ band structure of FASnI\textsubscript{3} supercell (32 f.u./cell). (b) The effective band structure (EBS) of the same FASnI\textsubscript{3} supercell, unfolded to the primitive Brillouin zone. The absorption spectra of (c) monomorphous cubic (1 f.u./cell) and (d) polymorphous cubic (32 f.u./cell) FASnI\textsubscript{3} and MAPbI\textsubscript{3}.

**Band edge states of the polymorphous network remain sharp, as does the absorption onset:** An attractive feature of the monomorphous Pm-3m structure is that its absorption spectrum\textsuperscript{48,49}
shows a sharp rise, which has been long used to explain why these materials are good solar energy absorbers. One might expect that the polymorphous ‘structural disorder’ associated with different distortions for different octahedra would create localized gap states as in traditional disorder models. This is difficult to evaluate from a supercell band structure (Fig. 4a) that folds-in a large number of bands, making it impossible to visually extract the \( E \) vs \( k \) dispersion.

To examine the important \( E \) vs \( k \) dispersion, we consider the Effective Band Structure (EBS) concept of band unfolding, yielding the EBS in the primitive Brillouin zone. One unfolds the supercell band structure by calculating the spectral weight \( P_{Km}(k_i) \) and from them the spectral function \( A(k_i, E) \), as illustrated in supplementary S-1c. Like the experimental Angle-Resolved Photoemission Spectroscopy (ARPES), EBS provides a 3-dimensional picture of the band edge wavefunctions at R point. This suggests that polymorphous cubic structures show sharp absorption edges, in fact, as sharp as that of the (fictive) undistorted monomorphous structure. This is in contradiction with the naïve view that octahedral deformations are a form of disorder.

Fig. 4b shows the EBS of a 32 f.u./cell of FASnI\(_3\) folded into the primitive Brillouin zone of the single cell. Every band now shows a mixed characteristic of coherent, ‘sharp’ dispersion and incoherent, ‘fuzzy’ broadening. Remarkably, the band edges (R point) are sharply dispersive despite the existence of a distribution of deformations that might appear as ‘disorder’. Concomitantly, the calculated absorption spectra in Fig. 4c and 4d (details in supplementary S-1d) of FASnI\(_3\) and MAPbI\(_3\) in the polymorphous cubic structures show sharp absorption edges, in fact, as sharp as that of the (fictive) undistorted monomorphous structure. This is in accord with the performance of such halide perovskites as superb absorbers, and in contradiction with the naïve view that octahedral deformations are a form of disorder.

Two factors may contribute to this. First, as discussed in the text surrounding the insert to Fig. 3a, octahedral deformations increase the band gap by moving the VBM to deeper energies, so this particular type of structural disorder displaces the would-be localized states into the band continuum, not the gap region. Second, the octahedral distortions couple only weakly to the band edge wavefunctions at R point. This is suggested by the great similarity in the hybridization of band edges (B-s with X-p in the VBM, and B-p with X-p in the CBM) before and after distortions, as shown in Supplementary Table S-7 and Fig. S-6 presenting large joint density of states and strong transition amplitude. This suggests that polymorphous octahedral distortions do not act as conventional disorder: while they shift band edges, they do not create localized gap states or band tail.

**Reconciling the contradiction about Phase-separation vs ordering:** Another physical property that depends on the definition of the structure of ABX\(_3\) is the alloy mixing enthalpy \( \Delta H'(A_xB_{1-x}) \) that measures the enthalpy \( H(A_xB_{1-x}) \) of an \( A_xB_{1-x} \) alloy taken with respect to equivalent amounts of the energies of the constituents \( xH(A) + (1-x)H(B) \). When \( H(A) \) and \( H(B) \) are calculated from the high-energy macroscopically averaged M-cubic structure, the resulting \( \Delta H'(A_xB_{1-x}) \) was often negative (Fig. 5, yellow shading) implying long range ordering at low temperature, which was never observed in halide perovskite alloys (either A-site, or B-site, or X-site alloys). Instead, phase segregation has been measured in experiment (e.g., for X site mixed alloys). Indeed, calculated excess enthalpy of mixed anion alloys MAPbI\(_{1-x}Br_x\)\(_3\) based on the monomorphous assumption by Goyal et al. reported negative alloy excess enthalpy, implying tendency of long-range order, which was never observed; instead,
Phase segregation has been measured for X site mixed alloys. As to mixed B-site alloys such MAPbSn1-xI3, no long-range order was observed and the existing samples of random alloys appear as single-phase disordered that are entropy stabilized. Because of the availability of this data, we calculated the same B site alloys FAPbSn1-xI3 in cubic phase finding that using the fictitious monomorphous structure (red lines and yellow shading) gives negative excess enthalpy, signaling incorrectly long range order, but using the polymorphous structure (green lines and green shading) gives (small) positive excess enthalpy, suggesting entropy stabilization at intermediate temperatures and phase separation at low temperatures (the latter may be difficult to observe because of the low atomic mobility at such low temperature). Thus, the monomorphous structures yield a contradiction with observed phase behavior, whereas the polymorphous is consistent with available data.

**Figure 5:** Alloy mixing enthalpies of FASnI3 and FAPbI3, with respect to monomorphous cubic (M-cubic) phases (yellow region) and polymorphous cubic (P-cubic) (green region), showing that the M-cubic values for the pure, non-alloyed compounds leads to negative enthalpy (implying ordering at low temperature), whereas the polymorphous network correctly predicts small positive mixing enthalpies (implying phase separation).

**Table III:** Calculated averaged macroscopic dielectric constants originated from ionic and electronic contributions of CsSnI3 by using DFPT theory.

<table>
<thead>
<tr>
<th>CsSnI3 structure</th>
<th>( \varepsilon ) (ionic)</th>
<th>( \varepsilon ) (electronic)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Monomorphous (1 f.u./cell)</td>
<td>35.11</td>
<td>54.97</td>
</tr>
<tr>
<td>Tetragonal (2 f.u./cell)</td>
<td>32.78</td>
<td>15.19</td>
</tr>
<tr>
<td>Orthorhombic (4 f.u./cell)</td>
<td>28.14</td>
<td>7.61</td>
</tr>
<tr>
<td>Polymorphous (32 f.u./cell)</td>
<td>128.23</td>
<td>8.08</td>
</tr>
</tbody>
</table>

*Enhancement of the dielectric constant and increased role of ionic vs electronic contribution in CsSnI3:* The near ferroelectric halide perovskites have large static dielectric constants whose magnitude is an important quantity in optical and defect theories. Our
Calculation of CsSnI$_3$ (Table III) shows that static dielectric constants of the assumed monomorphous phase is rather small ~35, with a 7:10 ratio between ionic and electronic contributions. However, for the polymorphous network we find a much higher static dielectric constant of 128, with a ratio of 16:1 between ionic and electronic contributions. This is close to the low frequency measurements of MAPbI$_3$ at high temperatures$^{58}$. Given hydrogen-like Wannier-Mott exciton model$^{59}$, large static dielectric constant$^{58}$ leads to small exciton binding energy, which benefits the separation of electron and hole.

![Diagram](image)

**Figure 6**: The spread of band gap (a), total energy (b) and pair distribution function (c) (using a uniform ADPs U$_{ij}$=0.01 Å$^2$) for the cubic CsPbI$_3$ (32 f.u./cell) for independently generated polymorphous networks using different initial nudges with randomly selected orientations and amplitudes ranging from 0.20 to 0.30 Å in steps of 0.01 Å. Results are compared to the monomorphous structure.

Are the properties of a polymorphous network unique for different polymorphous realizations? In an ensemble configuration such as the polymorphous network, it is possible that the total energy surface does not yield a narrow and sharp minimum corresponding to a single structure. To investigate the properties of independently generated polymorphous networks we use cubic, 32-f.u./cell (160-atom/cell) CsPbI$_3$ supercells as example: we minimize the internal DFT total energy for different randomly selected initial nudges (random on both direction and amplitude) on each atom and then relax all atomic positions (while constraining the macroscopic cubic lattice vectors) until the forces on all atoms within the supercells are below our standard tolerance of 0.01 eV/Å. Figure 6 shows the results for 11 independently
generated networks, giving the total energy distribution (Fig. 6a), band gap distributions (Fig. 6b), and calculated PDF profiles (Fig. 6c) of the relaxed structures, comparing them to the corresponding results of the monomorphous analogs. We see that the total energy variations among different randomly selected polymorphous realizations is <5 meV/atom with average deviation of 2.5 meV/atom, a difference that lies within the calculation tolerance, and is much smaller than the total energy difference between the monomorphous structure and the (average) polymorphous structure. Likewise, the band gaps of the different polymorphous realizations have a spread of 0.04 eV. Again, this spread is negligible relative to the band gap difference between the monomorphous structure 1.32 eV and the (average) polymorphous structure 1.85 eV. The different polymorphous realizations give consistent PDF in the distance range of 3.5-8.0 Å, and the calculated PDF is very different than PDF generated from the monomorphous structure. We conclude that the physical properties calculated from different realizations are robust and constitute a much more accurate representation than the use of the (unique, but incorrect) monomorphous structure, and is computationally much simpler (and cheaper) to obtain than electronic structure derived from dynamics.

VI. Implications and broader impact

Unstable monomorphous cubic perovskites can develop a set of energy lowering distribution of different local environments; such polymorphous networks are the kernels of what develops as temperature increases into the known high temperature phase seen in molecular dynamics simulation. This polymorphous network is different from the double potential well model of anharmonicity, and from the well-known octahedral tilting and rotation in orthorhombic ground state structures—both aforementioned cases correspond to single repeated ordered motifs. The calculated PDF, which probes the local environment, is much closer to experiment using low-energy polymorphous description instead of the monomorphous structure. Compared to the monomorphous assumption, the polymorphous networks lead to significantly lower calculated total energies, larger band gaps (with different trends among the sequence of ABX₃ compounds), much reduced band gap renormalization energies, reversal of the sign of the mixing enthalpies of the solid solutions from negative (ordering-like) to positive (phase-separating), and manifests a sharp absorption edge, all in agreement with experimental evidences.

The structure found by minimization of the internal energy part of the free energy is fully described by a distribution of geometric parameters relative to the ideal undistorted structure (Fig.1c). These are the essential geometric descriptor of the optimized polymorphous network, with only small fluctuations due to different, randomly initialized positional nudges of the atoms (Fig 6). There may be other ways to name the existence of different shapes (hence "polymorphic" i.e., "many shapes") of Fig. 1c, perhaps as complex structure in which there is a coexistence of sub-nano domains with different orientations, but these are just different words for describing the same calculated distribution of Fig. 1c.

The central point is that the minimization of the internal energy under the constrain of macroscopically cubic phase provides a very useful approximant to the physical configuration that can be used to calculate with standard DFT codes the physical properties (PDF, Fig. 2),
band structure (Fig. 4), Alloy physics (Fig. 5), band gaps (Table I), Dielectric constant (Table III) etc. in substantial agreement with experiment, and to remove many of the inconsistencies that existed previously between monomorphous DFT calculations and experiment. Thus, the polymorphous approximant could serve as a very useful practical structure to use with standard band structure approaches to predict properties. Thermal agitation is an additional contribution to our a-thermal descriptor (Fig. 3).

Figure 7: Statistics of motifs in perovskites for (a) BaTiO$_3$ (t=0.94), (b) TlBiO$_3$ (t=0.95) and (c) CsBiO$_3$ (t=1.01)

Not only in halide perovskites: The discussion on polymorphous networks in cubic halide perovskites focuses on *positional* polymorphism. There is also spin polymorphism (ie different local spin environments) noted earlier for electronic spin in paramagnetic 3d oxide$^{60,61}$ and in the paraelectric electronic polarization$^{62,63}$. The polymorphous cubic phases apply also to oxides that have dynamically unstable phonons, as shown in Fig. 7(a, b), *i.e.*, BaTiO$_3$, TlBiO$_3$, showing that this effect is not limited to halides. For comparison, we calculated also the relaxed total energy and band gaps of a compound that has *stable phonons* in the monomorphous structure, *i.e.*, CsBiO$_3$. BaTiO$_3$ was known$^3$ to manifest tilting and rotation, and our energy minimization of Fig. 7 shows that this is accommodated by developing a range of local environments, in particular for B site displacements. CsBiO$_3$ and TlBiO$_3$ were inferred to exist by Machine learning$^{33}$ but are not otherwise known compounds. We add them as calculated predictions for polymorphous behavior, correlating this with phonon stability vs instability in the hypothetical monomorphous structure. CsBiO$_3$ has stable phonons in the monomorphous structure and Fig. 7c shows that there are no polymorphous characters, *i.e.*, there is but uniformed tilting angle, negligible B-site off-center and change of volume. TlBiO$_3$ has phonon instability in the monomorphous structure and shows in Fig. 7b characteristic polymorphous behavior.
We note on closing that the related subject of nematicity—lowering of symmetry observed through electronic structure (local) probes with respect to the perceived global symmetry— as noted for example in FeSe\textsuperscript{64,65} is potentially closely related to polymorphous networks, where the existence of different local environments can lead to electronic symmetry breaking despite the existence of higher \textit{average} symmetry noted by global probes—Because polymorphism removes the centrosymmetric symmetry, one would expect also a Rashba effect and related optical measures of lowered symmetry.

We conclude that using polymorphous networks to replace fictitious monomorphous structures defines a broader principle of the need to describe broken-symmetry systems manifesting a range of microscopic configurations whose physical properties can be very different than the often-assumed macroscopic average.

\textbf{Acknowledgements}

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